RENESAS HD74LVC1G53

2-channel Analog Multiplexer/Demultiplexer

REJ03D0155-0300Z Rev.3.00 Jul. 02, 2004

Description

The HD74LVC1G53 has 2–channel analog multiplexer/demultiplexer in a 6-pin package. Applications include signal gating chopping, modulation or demodulation (modem), and signal multiplexing for analog to digital to analog conversion systems. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as renesas uni logic series.
- Supply voltage range: 1.65 to 5.5 V Operating temperature range: -40 to +85°C
- Control input: V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC1G53CPE	WCSP-6 pin	TBS-6V	CP	E (3,000 pcs/reel)
HD74LVC1G53CLE		TBS-6AV	CL	

Article Indication

Marking Year code KPÝM Month code	
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Function Table

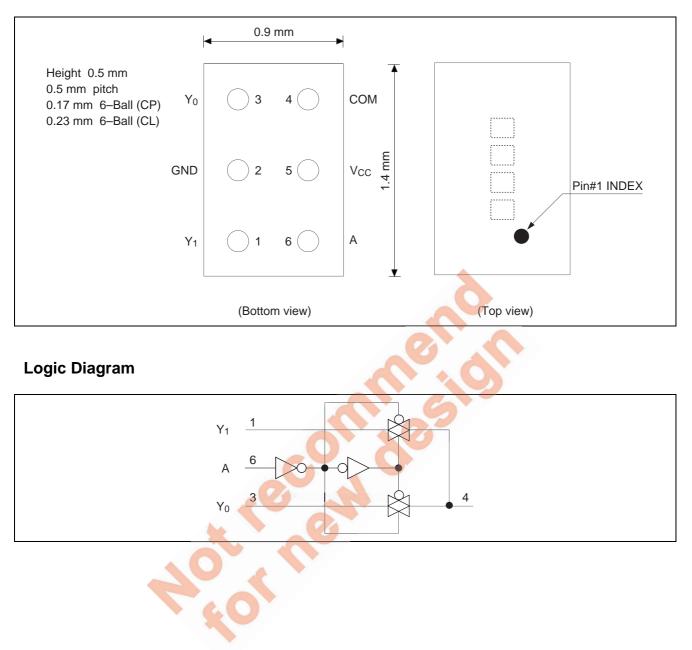
Control	On channel 1
L	Y ₀
Н	Y ₁

H: High level

L: Low level



Pin Arrangement





Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	–0.5 to 6.5	V	
Input voltage range *1	VI	-0.5 to 6.5	V	
Output voltage range *1, 2	Vo	–0.5 to V _{CC} +0.5	V	Output : H or L
Control Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Output clamp current	I _{ОК}	±50	mA	$V_0 < 0$ or $V_0 > V_{CC}$
Continuous output current	I _O	±50	mA	$V_0 = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±100	mA	
Package Thermal impedance	θ_{ja}	143	°C/W	CP
		123	1	CL
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

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2. This value is limited to 5.5 V maximum.

Recommended Operating Conditions

ltem	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Control Input voltage range	VI	0	5.5	V	
Input/Output voltage range	V _{I/O}	0	Vcc	V	
Input transition rise or fall rate	Δt / Δv	0	20	ns / V	V _{CC} = 1.65 to 1.95 V,
	1000				2.3 to 2.7 V
		0	10		V _{CC} = 3.0 to 3.6 V
		0	10		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature 🥢	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.



Electrical Characteristics

Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test condition
Input voltage	VIH	1.65 to 1.95	V _{cc} ×0.65	—	_	V	
		2.3 to 2.7	V _{CC} ×0.7	_	_		
		3.0 to 3.6	V _{CC} ×0.7	_	_		
		4.5 to 5.5	V _{CC} ×0.7	—	_		
	V _{IL}	1.65 to 1.95		—	V _{CC} ×0.35		
		2.3 to 2.7		_	V _{CC} ×0.3		
		3.0 to 3.6	_	—	V _{CC} ×0.3		
		4.5 to 5.5	—	—	V _{CC} ×0.3		
On-state switch	R _{ON}	1.65	_	13	30	Ω	$I_S = 4 \text{ mA}$ $V_I = V_{CC} \text{ or}$
resistance		2.3	_	10	20		I _S = 8 mA GND
		3.0	_	8.5	17		I _S = 24 mA
		4.5	_	6.5	13		I _S = 32 mA
Peak on resistance	R _{ON} (P)	1.65	_	86.5	120		$I_S = 4 \text{ mA}$ $V_I = V_{CC}$ to
		2.3	_	23	30		I _S = 8 mA GND
		3.0		13	20		I _S = 24 mA
		4.5	_	8	15		l _s = 32 mA
Difference of	ΔR_{ON}	1.65	_		7		$I_{\rm S} = 4 \text{ mA}$ $V_{\rm I}=V_{\rm CC}$ to
on-state resistance		2.3	_	\leq	5	2	I _S = 8 mA GND
between switches		3.0	_		3		I _S = 24 mA
		4.5	_	-	2		I _S = 32 mA
Off-state switch	I _{S (OFF)}	5.5	-01	-	±1.0	μA	$V_I = V_{CC}$ and $V_O = GND$ or
leakage current				-	±0.1* ¹		$V_I = GND$ and $V_O = V_{CC}$,
							$V_A = V_{IL}, V_{IH}$
On-state switch	I _{S (ON)}	5.5			±1.0	μA	$V_I = V_{CC}$ or GND,
leakage current			- 0	-	±0.1* ¹		$V_A = V_{IH}, V_{IL}$
O e esta e l'in e e et					.1.0	•	$V_0 = Open$
Control input current	I _{IN}	5.5		_	±1.0 ±0.1* ¹	μA	$V_{IN} = V_{CC}$ or GND
				_		•	
Quiescent	lcc	5.5		_	10 1.0* ¹	μA	$V_{IN} = V_{CC}$ or GND
supply current			_	_			
O and the line of		5.5	<u> </u>	_	500	μA	$V_{\rm C} = V_{\rm CC} - 0.6 \text{ V}$
Control input	CIC	5.0	—	3.0	 	pF	
capacitance		5.0		6.0			
Switch terminal capacitance	CI/O(OFF)	5.0		6.0	—	pF	
Noto: $1 T_2 = 25^{\circ}$	CI/O(ON)	5.0	—	13	—		

Note: 1. Ta = 25°C

Switching Characteristics

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

		Ta = -4	0 to 85°C			FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time*1	t _{PLH}		2.0	ns	$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	COM or Yn	Yn or COM
	t _{PHL}						
Enable time	t _{zH}	2.9	10.3		$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	А	Yn
	t _{ZL}						
Disable time	t _{HZ}	2.1	9.4		$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	A	Yn
	t _{LZ}						

 $V_{CC}=2.5\pm0.2~V$

		Ta = -40) to 85°C			FROM	то
ltem	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time*1	t _{PLH}		1.2	ns	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	COM or Yn	Yn or COM
	t _{PHL}						
Enable time	t _{ZH}	2.1	7.2		$C_{L} = 30 \text{ pF}, R_{L} = 500 \Omega$	A	Yn
	t _{ZL}						
Disable time	t _{HZ}	1.4	7.9		$C_{L} = 30 \text{ pF}, R_{L} = 500 \Omega$	A	Yn
	t _{LZ}						

		Ta = -4	0 to 85°C			FROM	= 3.3 ± 0.3 \ TO
Item	ymbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time* ¹	t _{PLH} t _{PHL}		0.8	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	COM or Yn	Yn or COM
Enable time	t _{ZH} t _{ZL}	1.9	5.8		$C_{L} = 50 \text{ pF}, \text{ R}_{L} = 500 \Omega$	A	Yn
Disable time	t _{HZ} t _{LZ}	1.1	7.2		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	A	Yn

$V_{CC} = 5.0 \pm 0.5 \text{ V}$

						•	- 5.0 ± 0.5 1
		Ta = -40) to 85°C			FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time* ¹	t _{PLH}		0.6	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	COM or Yn	Yn or COM
	t _{PHL}						
Enable time	t _{ZH}	1.3	5.4		$C_{L} = 50 \text{ pF}, R_{L} = 500 \Omega$	A	Yn
	tZL						
Disable time	t _{HZ}	1.0	5.0]	$C_{L} = 50 \text{ pF}, R_{L} = 500 \Omega$	A	Yn
	t _{LZ}						

Notes: 1. The propagation delay is calculated RC time constant of typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



Analog Switch Characteristics

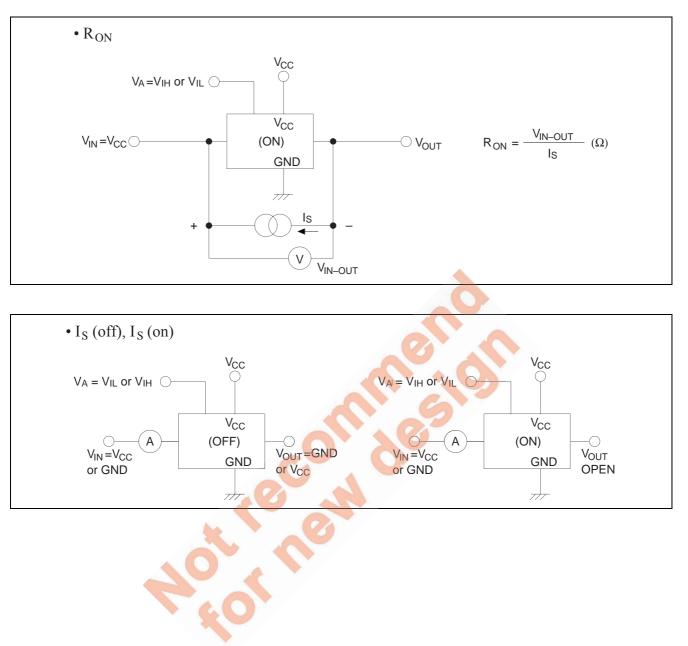
		Т	a = 25°	°C				FROM	то
Item	V _{cc} (V)	Min	Тур	Max	Unit		Test conditions	(Input)	(Output)
Frequency response	1.65	—	35	—	MHz	$C_{L} = 50 \text{ pF},$	Adjust fin voltage to obtain	COM or	Y or
(Switch ON)	2.3	—	120			$R_L = 600 \Omega$	0dBm at output when fin is	Y	СОМ
	3.0	—	190			_	1MHz (sine wave).		
	4.5	—	215				Increase fin frequency until		
	1.65	_	>300			C _L = 5 pF,	the dB-meter reads -3 dBm.		
	2.3	_	>300	_		$R_L = 50 \Omega$	$20 \log(V_0/V_1) = -3 \text{ dBm}$		
	3.0	_	>300						
	4.5		>300						
Crosstalk	1.65	_	-58	_	dB	$C_{L} = 50 \text{ pF},$	Adjust fin voltage to obtain	СОМ	Y
(between switches)	2.3	_	-58	_		$R_L = 600 \Omega$	0dBm at input when fin is		
	3.0	_	-58	_			1MHz (sine wave).		
	4.5	_	-58	_					
	1.65	—	-42			$C_L = 5 \text{ pF},$]		
	2.3	—	-42			$R_L = 50 \Omega$			
	3.0		-42			-			
	4.5		-42						
Crosstalk	1.65	—	35		mV	$C_{L} = 50 \text{ pF},$	Adjust RL value to obtain 0A	A	Y or
(Control input to signal	2.3	_	50	_		$R_L = 600 \Omega$	at IIN/OUT when fin is 1MHz		СОМ
output)	3.0		70			-	(square wave)		
	4.5		100						
Feed through	1.65	_	-58	_	dB	$C_{L} = 50 pF$,	Adjust fin voltage to obtain	COM or	Y or
attenuation	2.3	—	-58			$R_L = 600 \Omega$	0dBm at input when fin is	Y	СОМ
(Switch OFF)	3.0	_	-58	_			1MHz (sine-wave)		
,	4.5	_	-58	-					
	1.65	—	-42	- / /		$C_L = 5 \text{ pF},$			
	2.3	—	-42	-		$R_L = 50 \Omega$			
	3.0	—	-42	-7/					
	4.5	_	-42						
Sine-wave distortion	1.65	- /	0.1	-	%	$C_{L} = 50 pF$,	V _I =1.4V _{P-P} , V _{CC} =1.65V	COM or	Y or
	2.3		0.025	—		$R_L = 10 k\Omega$	$V_{I}=2.0V_{P-P}, V_{CC}=2.3V$	Y	СОМ
	3.0	10	0.015	_		fin = 1kHz	V _I =2.5V _{P-P} , V _{CC} =3.0V		
	4.5		0.01	ê.		(sine-wave)	$V_{I}=4.0V_{P-P}, V_{CC}=4.5V$		
	1.65		0.15			$C_L = 50 \text{ pF},$			
	2.3	_	0.025		1	$C_L = 50 \text{ pr},$ $R_L = 10 \text{ k}\Omega$			
	3.0		0.015			$R_L = 10 \text{ k}\Omega$ fin = 10kHz			
	4.5	_	0.01	_					
		1	0.01			(sine-wave)			

Operating Characteristics

			Ta = 25°C					
Item	Symbol	Vcc (V)	Min	Тур	Max	Unit	Test Conditions	
Power dissipation capacitance	CPD	1.8	—	9	—	pF	f = 10 MHz	
		2.5	—	10				
		3.3	—	10	—			
		5.0	_	12				

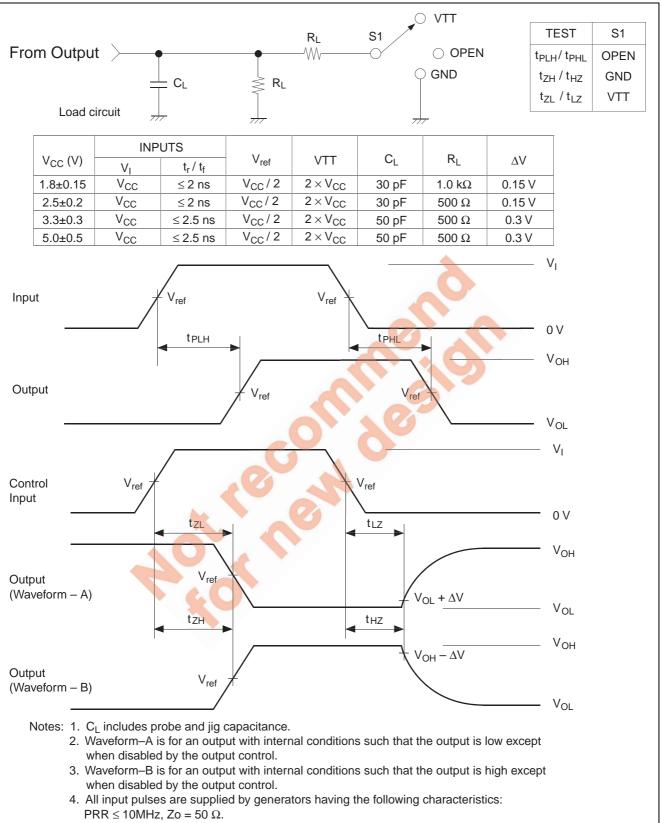


Test Circuit



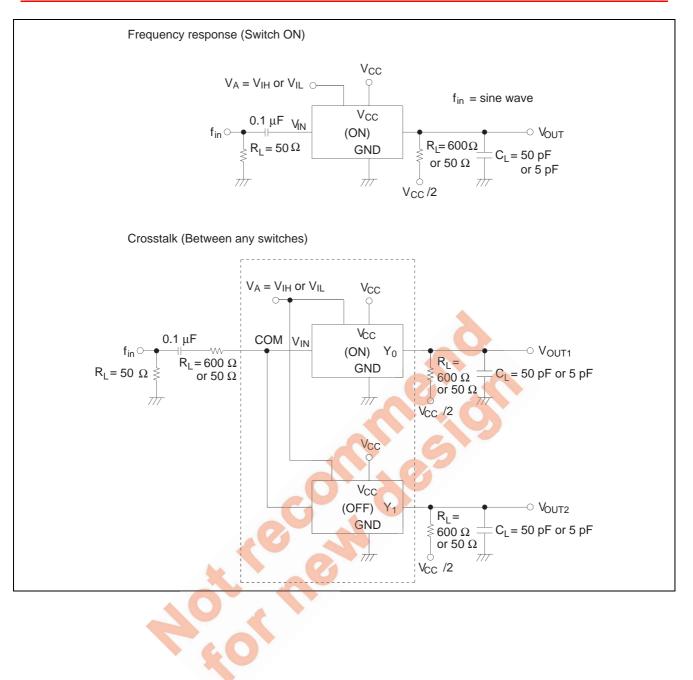


Test Circuit (cont.)

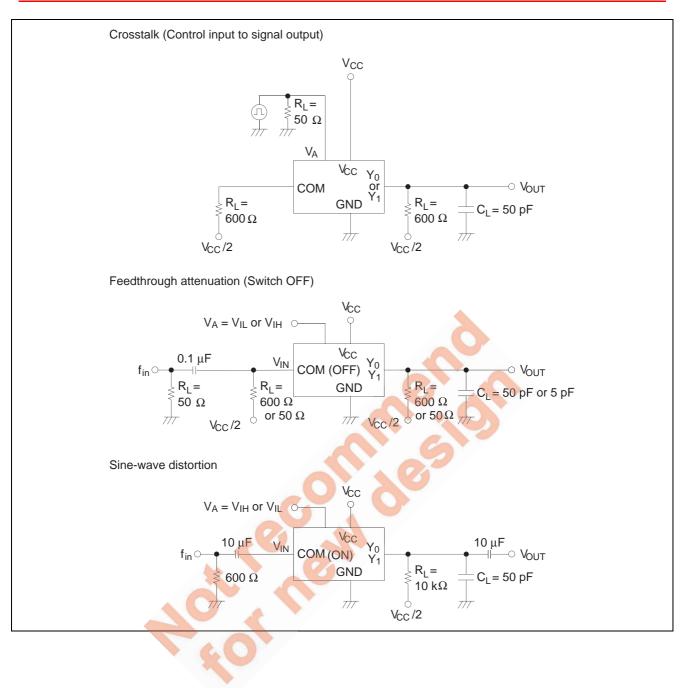


5. The output are measured one at a time with one transition per measurement.



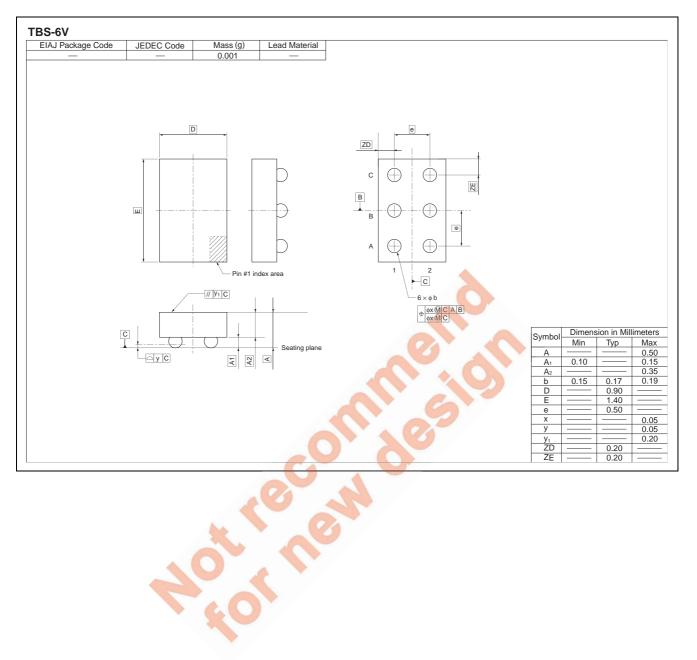








Package Dimensions





HD74LVC1G53

BS-6AV	'				
EIAJ Package Code	JEDEC Code	Mass (g) 0.001	Lead Material		
[C C C C C C C C C C C C C C C C C C C		dex area		$\begin{array}{ c c c c c c c c c c c c c c c c c c c$
					y1 0.20 ZD 0.20 ZE 0.20
			eco		

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